

	Type	L #	Hits	Search Text	DBs	Time Stamp	Co mm en ts	Er ro r De fi ni ti on	Er ro rs
1	IS&R	L1	2	("4556975").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 13:19			
2	IS&R	L2	2	("4672240").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 13:19			
3	IS&R	L3	2	("5153880").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 13:20			
4	IS&R	L4	2	("5353431").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 13:20			
5	IS&R	L5	2	("6740928").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 13:57			
6	IS&R	L6	2	("6952032").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 13:58			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Co mm en ts	Er ro r De fi ni ti on	Er ro rs
7	IS&R	L7	2	("6950340").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 13:59			
8	IS&R	L8	2	("6521943").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 13:59			
9	IS&R	L9	2	("6504207").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 13:59			
10	IS&R	L10	2	("5973355").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 14:00			
11	IS&R	L11	2	("20050169054").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 14:01			
12	IS&R	L12	2	("20020109138").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 14:02			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
13	BRS	L15	0	hot with channel with electron with inject\$5 and (second or \$3other or two) near logic near plane and sum near of near product and eras\$5 with float\$4 adj gate with electron with tunnel\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 14:17			
14	BRS	L16	3	hot with channel with electron with inject\$5 and (second or \$3other or two) with logic with plane and sum near product and eras\$5 with float\$4 adj gate with electron with tunnel\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 14:22			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
15	BRS	L13	12	(second or \$3other or two) near logic near plane and float\$4 adj gate with polysilicon and float\$4 adj gate with metal and tunnel near barrier with metal with float\$4 adj gate and (row with column or array)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 14:20			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
16	BRS	L14	12	(second or \$3other or two) near logic near plane and control\$4 adj gate with polysilicon and control\$4 adj gate with metal and tunnel near barrier with metal with control\$4 adj gate and (row with column or array)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 14:22			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Co mm en ts	Er ro r De fi ni ti on	Er ro rs
17	BRS	L17	10	((second or \$3other or two) near logic near plane and control\$4 adj gate with polysilicon and control\$4 adj gate with metal and tunnel near barrier with metal with control\$4 adj gate and (row with column or aray)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 14:22			
18	BRS	L18	0	(hot with channel with electron with inject\$5 and (second or \$3other or two) with logic with plane and sum near product and eras\$5 with float\$4 adj gate with electron with tunnel\$4).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/12/29 14:22			